## **IFUNCTION TABLE**

	Inp	Outputs			
Preset	Clear	Clock	D	Q	Q
L	Н	×	×	Н	L
Н	L	×	×	L	Н
L	L	×	×	H*	Н*
Н	Н	1	Н	Н	L
Н	Н	1	L	L	Н
Н	Н	L	×	Qo	$\overline{\mathbf{Q}}_{0}$

Notes) H; high level, L; low level, X; irrelevant

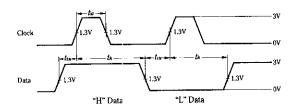
t; transition from low to high level

 $Q_o$ ; level of Q before the indicated steady-state conditions were established.

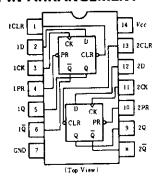
O<sub>o</sub>; complement of Q<sub>o</sub> or level of Q before the indicated steady-state input conditions were established.

\*: This configuration is nonstable, that is, it will not persist when preset and clear inputs return to their inactive (high) level.

# **TIMING DEFINITION**



## **■PIN ARRANGEMENT**



# **ERECOMMENDED OPERATING CONDITIONS**

Item Clock frequency		Symbol	min	typ	max	Unit MH2	
		felock	0		25		
Pulse	Clock High		25	_	_		
width	Clear Preset	tw	25	_		ns	
Setup	"H"Data		201	_			
time "L"Data		tsu	20↑	_	-	ns	
Hold time		th.	5↑	_	_	ns	

Note) †; The arrow indicates the rising edge.

# **ELECTRICAL CHARACTERISTICS** ( $Ta = -20 \sim +75$ °C)

Item		Symbol	Test Conditions		min	typ*	max	Unit
		ViH			2.0	_	_	v
Input voltage		VIL			-		0.8	v
		Voн	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V}, I_{OH} = -400 \mu\text{A}$		2.7		-	v
Output voltage		Vol	$V_{CC} = 4.75 \text{V},  V_{IL} = 0.8 \text{V},$	$I_{OL} = 8 \text{m A}$			0.5	v
			$V_{IH} = 2V$	$I_{OL} = 4 \mathrm{mA}$	T -		0.4	
	D						20	μΑ
	Clear					_	40	
	Preset	Itн	$V_{cc} = 5.25 \text{V},  V_{l} = 2.7 \text{V}$	1=2.1V			40	
	Clock					_	20	
	D					-	-0.4	
	Clear		$V_{\rm CC} = 5.25  \text{V},  V_{\rm f} = 0.4  \text{V}$	_	-	-0.8		
Input current	Preset	ItL				-	-0.8	mA
	Clock						-0.4	]
	D				T	_	0.1	
	Clear		T				0.2	mA
	Preset	Iı	$V_{CC} = 5.25 \text{V},  V_I = 7 \text{V}$	= / V			0.2	
	Clock						0.1	
Short-circuit output current		Ios	Vcc=5.25V		-20	_	-100	mA
Supply current		Icc**	Vcc=5.25V		_	4	8_	mA
Input clamp voltage		Vik	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$		T -	-	-1.5	V

\* V<sub>CC</sub>=5V, Ta=25°C

\*\* With all outputs open,  $I_{CC}$  is measured with the Q and  $\overline{\mathbb{Q}}$  outputs high in turn. At the time of measurement, the clock input is grounded.

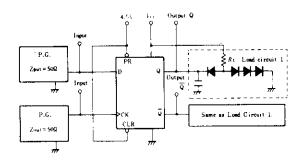
# **E**SWITCHING CHARACTERISTICS (Vcc=5V, $Ta=25^{\circ}C$ )

Item	Symbol	Inputs	Outputs	Test Condition	min	typ	max	Unit
Maximum clock frequency	fmax.			<del>"</del>	25	33		MHz
Propagation delay time	tp i.H	Clock, Clear	Q, Q	$C_L = 15 \mathrm{pF}, R_L = 2 \mathrm{k}\Omega$		13	25	ns
	tPHL	or Preset			_	25	40	ns

## **TESTING METHOD**

1) Test Circuit

1.1)  $f_{max}$ ,  $t_{PLH}$ ,  $t_{PHL}$  (Clock $\rightarrow$ Q, $\overline{Q}$ )

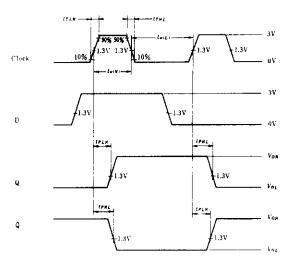


Notes) 1. Test is put into the each flip-flop

2. All diodes are 1S2074 (B).

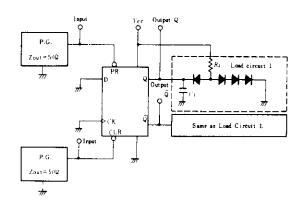
3.  $C_L$  includes probe and jig capacitance.

#### Waveform



Note) Clock input pulse;  $t_{TLH} \le 15$ ns,  $t_{THL} \le 6$ ns, PRR = 1MH2, duty cycle=50% and: for  $f_{max}$ ,  $t_{TLH} = t_{THL} \le 2.5$ ns.

## 1.2) tpHL, tpLH (Clear or Preset→Q,Q)

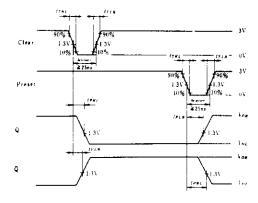


Notes) 1. Test is put into the each flip-flop

2. All diodes are 1S2074 (B).

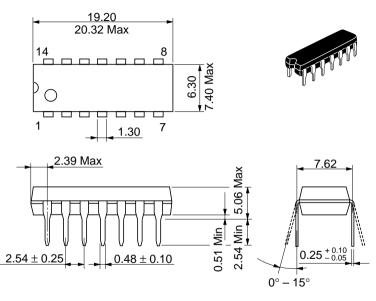
3. C<sub>L</sub> includes probe and jig capacitance.

#### Waveform



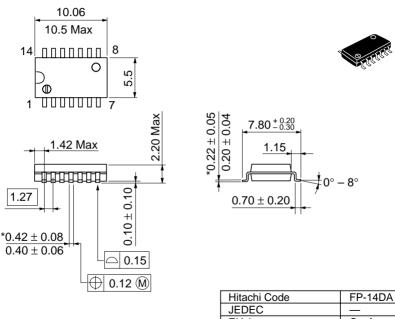
Note) Clear and preset input pulse;  $t_{TLH} \le 15 \text{ns}, t_{THL} \le 6 \text{ns},$ PRR = 1 MHz

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

Unit: mm



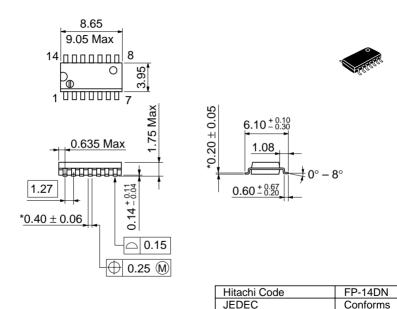
\*Dimension including the plating thickness
Base material dimension

\*Dimension including the plating thickness

Base material dimension

Weight (reference value) 0.23 g

Unit: mm



EIAJ

Weight (reference value)

Conforms

0.13 g

\*Pd plating

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